

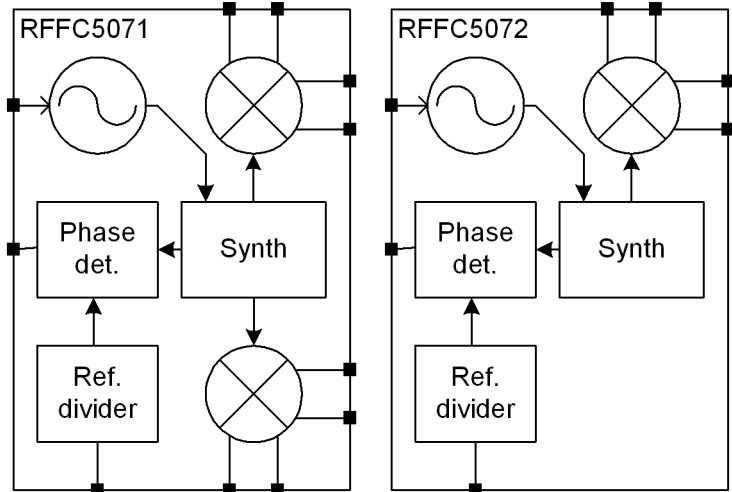


**Features**

- 85MHz to 4200MHz LO Frequency Range
- Fractional-N Synthesizer with Very Low Spurious Levels
- Typical Step Size 1.5Hz
- Fully Integrated Low Phase Noise VCO and LO Buffers
- High Linearity RF Mixer(s)
- 30MHz to 6000MHz Mixer Frequency Range
- Input IP3 +23dBm
- Mixer Bias Adjustable for Low Power Operation
- Full Duplex Mode (RFMC5071)
- 2.7V to 3.3V Power Supply
- Low Current Consumption
- 3- or 4-Wire Serial Interface

**Applications**

- Diversity Receivers
- Software Defined Radios
- Wideband Radios
- Frequency Band Shifters
- Point-to-Point Radios
- WiMax/LTE Infrastructure
- Satellite Communications



Functional Block Diagram

**Product Description**

The RFMC5071 and RFMC5072 are reconfigurable frequency conversion devices with integrated fractional-N phased locked loop (PLL) synthesizer, voltage controlled oscillator (VCO) and either one or two high linearity mixers. The fractional-N synthesizer takes advantage of an advanced sigma-delta modulator that delivers ultra-fine step sizes and low spurious products. The PLL/VCO engine combined with an external loop filter allows the user to generate local oscillator (LO) signals from 85MHz to 4200MHz. The LO signal is buffered and routed to the integrated RF mixers which are used to convert frequencies ranging from 30MHz to 6000MHz. The mixer bias current is programmable and can be reduced for applications requiring lower power consumption.

Both devices can be configured to work as signal sources by bypassing the integrated mixers. Device programming is achieved via a simple 3-wire serial interface. In addition, a unique programming mode allows up to four devices to be controlled from a common serial bus. This eliminates the need for separate chip-select control lines between each device and the host controller. Up to six general purpose outputs are provided, which can be used to access internal signals (e.g. the LOCK signal) or to control front end components. Both devices operate with a 2.7V to 3.3V power supply.

**Optimum Technology Matching® Applied**

- |                                      |                                      |   |                                    |
|--------------------------------------|--------------------------------------|---|------------------------------------|
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| <input type="checkbox"/> GaAs MESFET | <input type="checkbox"/> Si BiCMOS   | <input checked="" type="checkbox"/> Si CMOS | <input type="checkbox"/> BIFET HBT |
| <input type="checkbox"/> InGaP HBT   | <input type="checkbox"/> SiGe HBT    | <input type="checkbox"/> Si BJT             | <input type="checkbox"/> LDMOS     |

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## Absolute Maximum Ratings

| Parameter                          | Rating                 | Unit |
|------------------------------------|------------------------|------|
| Supply Voltage ( $V_{DD}$ )        | -0.5 to +3.6           | V    |
| Input Voltage ( $V_{IN}$ ) any pin | -0.3 to $V_{DD} + 0.3$ | V    |
| RF/IF mixer input power            | +15                    | dBm  |
| Operating Temperature Range        | -40 to +85             | °C   |
| Storage Temperature Range          | -40 to +150            | °C   |



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

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| Parameter   | Specification  |      |                | Unit  | Condition                                     |
|---|----------------|------|----------------|-------|---|
|   | Min.           | Typ. | Max.           |       |   |
| <b>ESD Requirements</b>   |                |      |                |       |   |
| Human Body Model  | 2000           |      |                | V     | General                                       |
|   | 1000           |      |                | V     | RF Pins                                       |
| Machine Model   | 200            |      |                | V     | General                                       |
|   | 100            |      |                | V     | RF Pins                                       |
| <b>Operating Conditions</b>   |                |      |                |       |   |
| Supply voltage ( $V_{DD}$ )   | 2.7            | 3.0  | 3.3            | V     |   |
| Temperature ( $T_{OP}$ )  | -40            |      | +85            | °C    |   |
| <b>Logic Inputs/Outputs (<math>V_{DD}</math>=Supply to DIG_VDD pin)</b> |                |      |                |       |   |
| Input low voltage   | -0.3           |      | +0.5           | V     |   |
| Input high voltage  | 1.5            |      | $V_{DD}$       | V     |   |
| Input low current   | -10            |      | +10            | μA    | Input=0V                                      |
| Input high current  | -10            |      | +10            | μA    | Input= $V_{DD}$                               |
| Output low voltage  | 0              |      | $0.2 * V_{DD}$ | V     |   |
| Output high voltage   | $0.8 * V_{DD}$ |      | $V_{DD}$       | V     |   |
| Load resistance   | 10             |      |                | kΩ    |   |
| Load capacitance  |                |      | 20             | pF    |   |
| <b>Static</b>   |                |      |                |       |   |
| Supply Current ( $I_{DD}$ ) with 1GHz LO                                |                | 100  |                | mA    | Low current, MIX_IDD=1, one mixer enabled.    |
|   |                | 125  |                | mA    | High linearity, MIX_IDD=6, one mixer enabled. |
| Standby   |                |      | 2              | mA    | Reference oscillator and bandgap only.        |
| Power Down Current  |                |      | 300            | μA    | ENBL=0 and REF_STBY=0                         |
| <b>Mixer 1/2 (Mixer output driving 4:1 balun)</b>                       |                |      |                |       |   |
| Gain  |                | -2   |                | dB    | Not including balun losses                    |
| Noise Figure  |                | 10   |                | dB    | Low current setting                           |
|   |                | 13   |                | dB    | High linearity setting                        |
| IIP3  |                | +10  |                | dBm   | Low current setting                           |
|   |                | +23  |                | dBm   | High linearity setting                        |
| Input port frequency range  | 30             |      | 6000           | MHz   |   |
| Mixer input return loss   |                | 10   |                | dB    | 100Ω differential                             |
| Output port frequency range   | 30             |      | 4500           | MHz   |   |
| <b>Reference Oscillator</b>   |                |      |                |       |   |
| External reference frequency  | 10             |      | 104            | MHz   |   |
| Reference divider ratio   | 1              |      | 7              |       |   |
| External reference input level  | 500            | 800  | 1500           | mVp-p | AC-coupled                                    |

| Parameter   | Specification |      |      | Unit   | Condition                         |
|---|---------------|------|------|--------|-----------------------------------|
|   | Min.          | Typ. | Max. |        |                                   |
| <b>Synthesizer (Loop bandwidth of 200 KHz, 52MHz reference)</b> |               |      |      |        |                                   |
| Synthesizer output frequency                                    | 85            |      | 4200 | MHz    |                                   |
| Phase detector frequency  |               |      | 52   | MHz    |                                   |
| Phase noise (LO=1GHz)   |               | -108 |      | dBc/Hz | 10kHz offset                      |
|   |               | -108 |      | dBc/Hz | 100kHz offset                     |
|   |               | -135 |      | dBc/Hz | 1MHz offset                       |
|   |               | 0.19 |      | °      | RMS integrated from 1kHz to 40MHz |
| Phase noise (LO=2GHz)   |               | -102 |      | dBc/Hz | 10kHz offset                      |
|   |               | -102 |      | dBc/Hz | 100kHz offset                     |
|   |               | -130 |      | dBc/Hz | 1MHz offset                       |
|   |               | 0.32 |      | °      | RMS integrated from 1kHz to 40MHz |
| Normalized phase noise floor                                    |               | -214 |      | dBc/Hz | Measured at 20kHz to 30kHz offset |

| Pin            | Function   | Description  |
|----------------|------------|--|
| 1              | ENBL/GPO5  | Device Enable pin. See note 1 and 2.   |
| 2              | EXT_LO     | External local oscillator input.   |
| 3              | EXT_LO_DEC | Decoupling pin for external local oscillator.                                      |
| 4              | REXT       | External bandgap bias resistor. See note 3.  |
| 5              | ANA_VDD1   | Analog supply. Use good RF decoupling.   |
| 6              | LFILT1     | Phase detector output. Low-frequency noise-sensitive node.                         |
| 7              | LFILT2     | Loop filter op-amp output. Low-frequency noise-sensitive node.                     |
| 8              | LFILT3     | VCO control input. Low-frequency noise-sensitive node.                             |
| 9              | MODE/GPO6  | Mode select pin. See note 1 and 2.   |
| 10             | REF_IN     | Reference input. Use AC coupling capacitor.  |
| 11             | NC         |  |
| 12             | TM         | Connect to ground.   |
| 13             | MIX1_IPN   | Differential input 1 (see note 4). On RFFC5072 this pin is NC.                     |
| 14             | MIX1_IPP   | Differential input 1 (see note 4). On RFFC5072 this pin is NC.                     |
| 15             | GPO1/ADD1  | General purpose output / MultiSlice address bit.                                   |
| 16             | GPO2/ADD2  | General purpose output / MultiSlice address bit.                                   |
| 17             | MIX1_OPN   | Differential output 1 (see note 5). On RFFC5072 this pin is NC.                    |
| 18             | MIX1_OPP   | Differential output 1 (see note 5). On RFFC5072 this pin is NC.                    |
| 19             | DIG_VDD    | Digital supply. Should be decoupled as close to the pin as possible.               |
| 20             | NC         |  |
| 21             | NC         |  |
| 22             | ANA_VDD2   | Analog supply. Use good RF decoupling.   |
| 23             | MIX2_IPP   | Differential input 2 (see note 4).   |
| 24             | MIX2_IPN   | Differential input 2 (see note 4).   |
| 25             | GPO3/FM    | General purpose output / frequency control input.                                  |
| 26             | GPO4/LD/DO | General purpose output / Lock detect output / serial data out.                     |
| 27             | MIX2_OPN   | Differential output 2 (see note 5).  |
| 28             | MIX2_OPP   | Differential output 2 (see note 5).  |
| 29             | RESETX     | Chip reset (active low). Connect to DIG_VDD if asynchronous reset is not required. |
| 30             | ENX        | Serial interface select (active low). See note 1.                                  |
| 31             | SCLK       | Serial interface clock. See note 1.  |
| 32             | SDATA      | Serial interface data. See note 1.   |
| Exposed paddle |            | Ground reference, should be connected to PCB ground through a low impedance path.  |

Note 1: An RC low-pass filter could be used on this line to reduce digital noise.

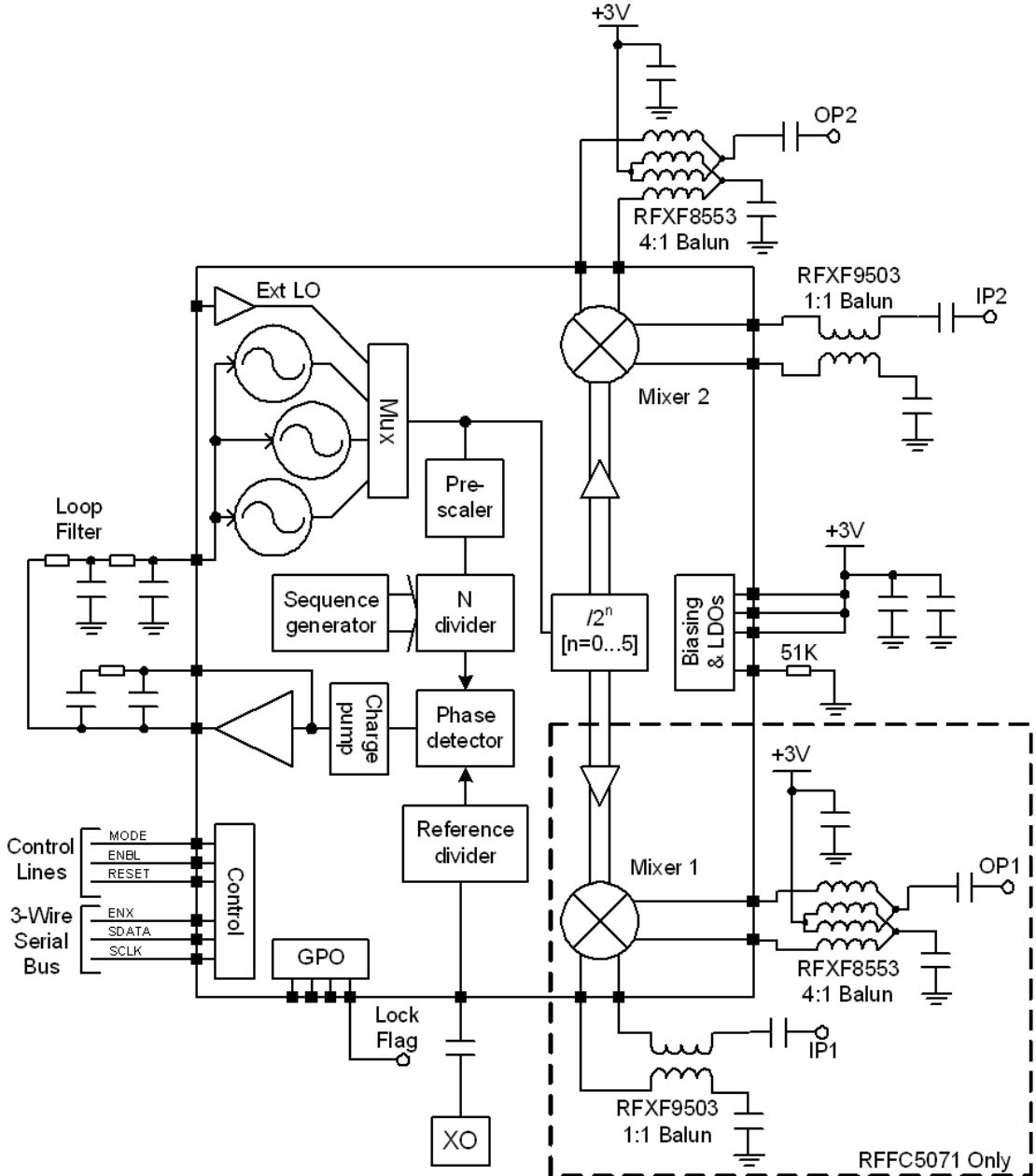
Note 2: If the device is under software control this input can be configured as a general purpose output (GPO).

Note 3: Connect a 51KΩ resistor from this pin to ground. This pin is sensitive to low frequency noise injection.

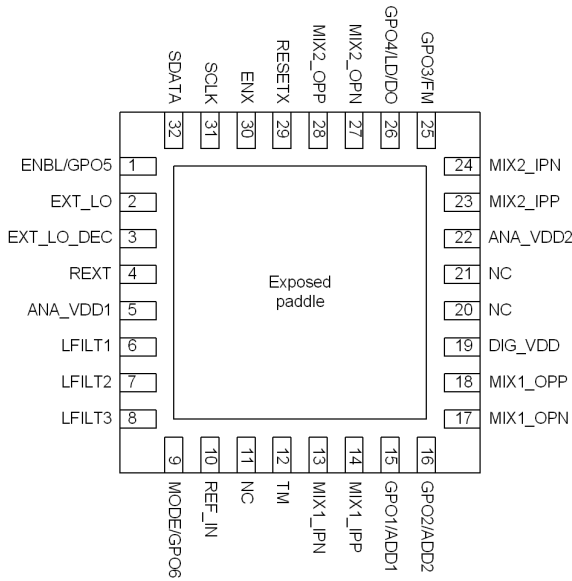
Note 4: DC voltage should not be applied to this pin. Use either an AC coupling capacitor as part of lumped element matching network or a transformer (see evaluation board schematic).

Note 5: This pin must be connected to ANA\_VDD2 using an RF choke or center-tapped transformer (see evaluation board schematic).

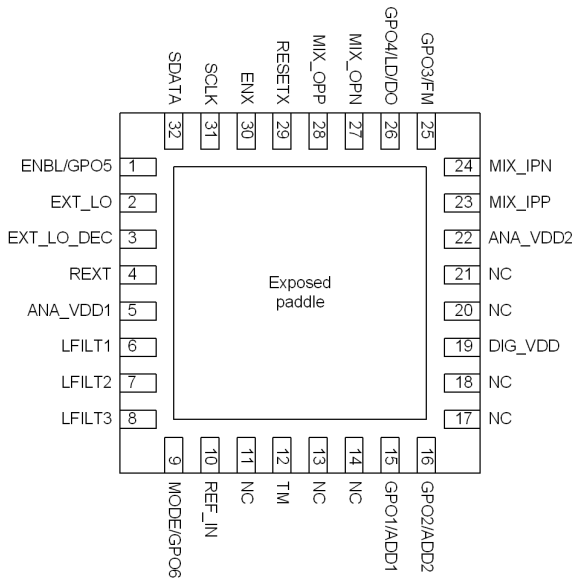
**Detailed Functional Block Diagram**



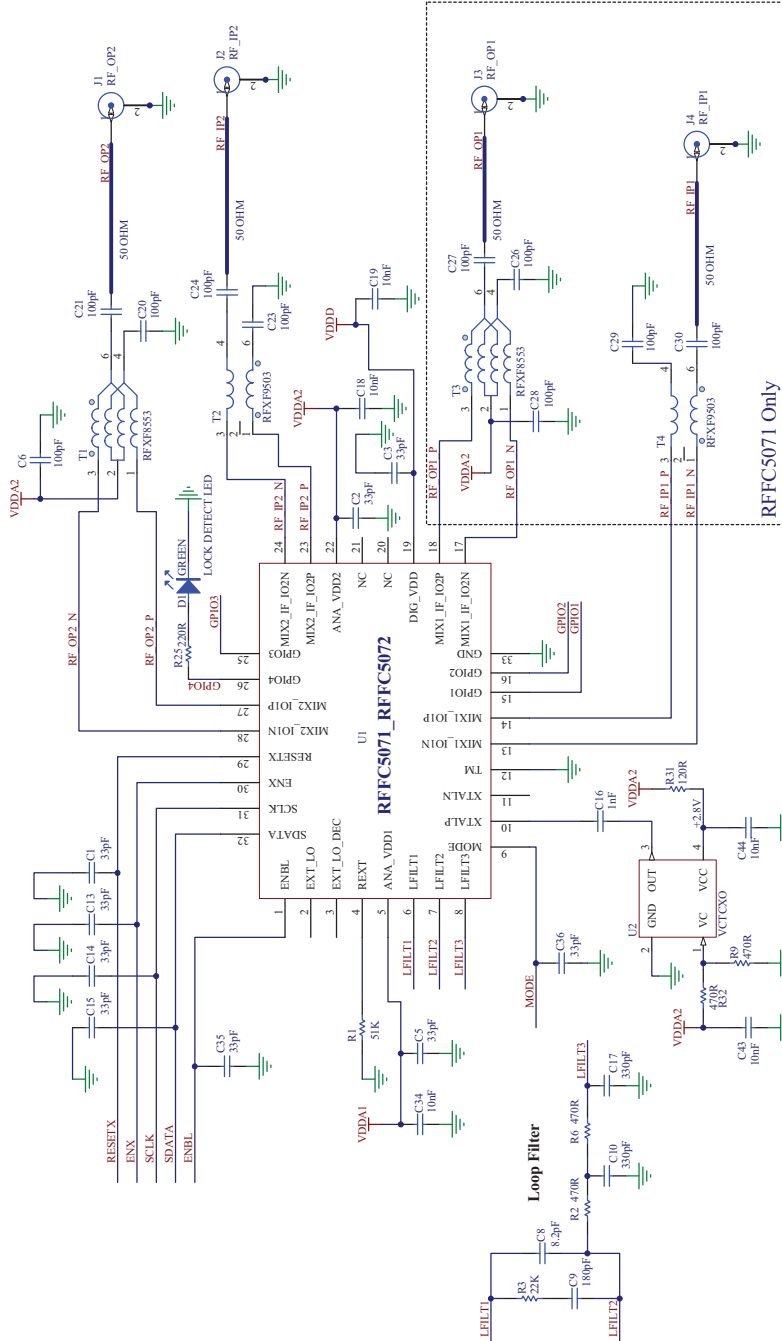
## RFFC5071 Pin Out



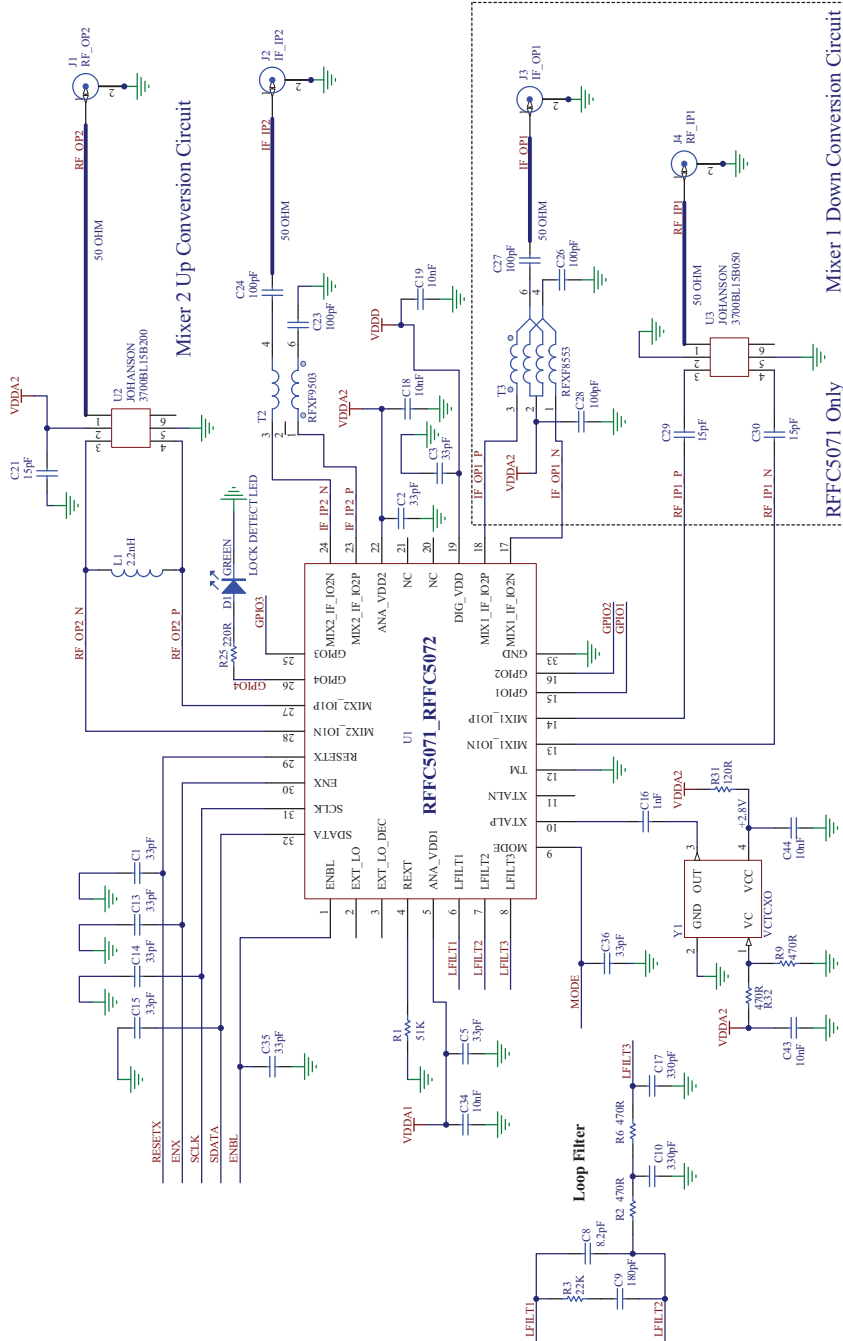
## RFFC5072 Pin Out



**Wideband Application Schematic**



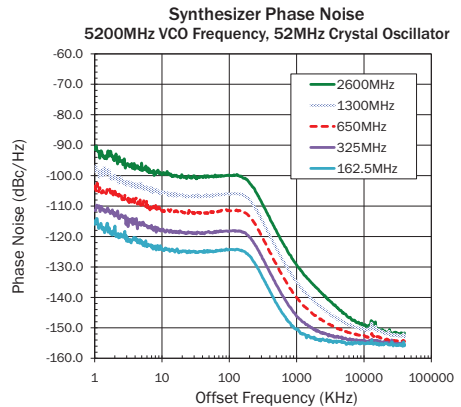
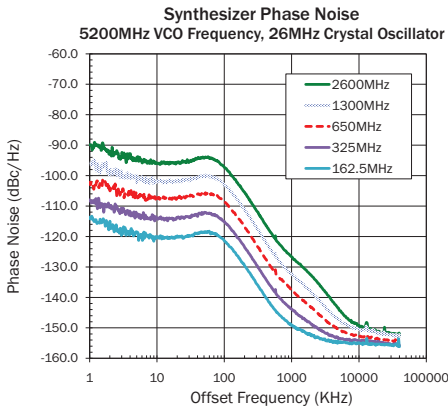
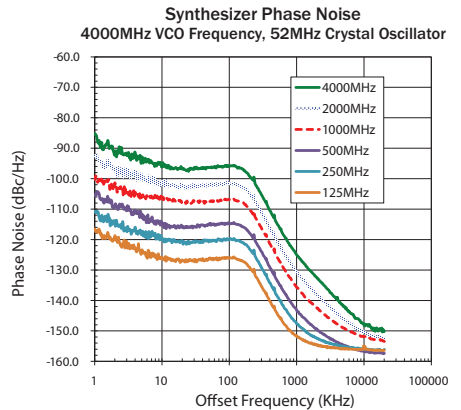
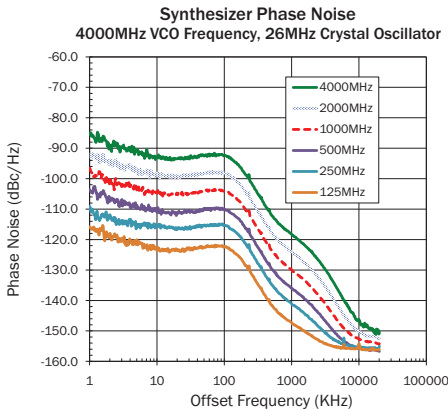
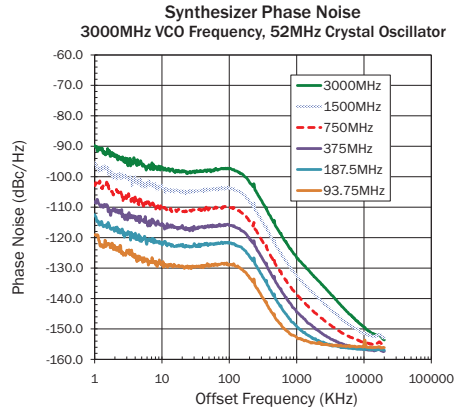
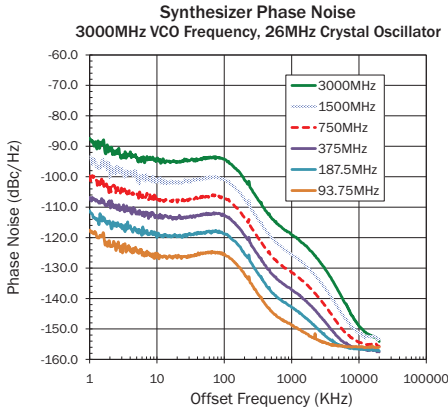
## Narrowband 3.7GHz Application Schematic





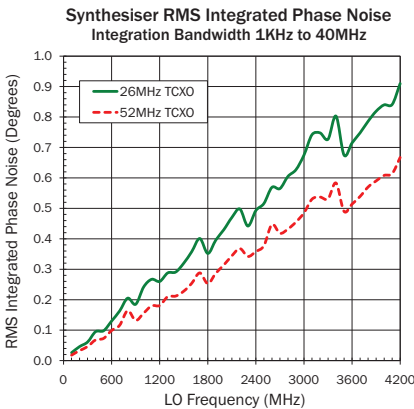
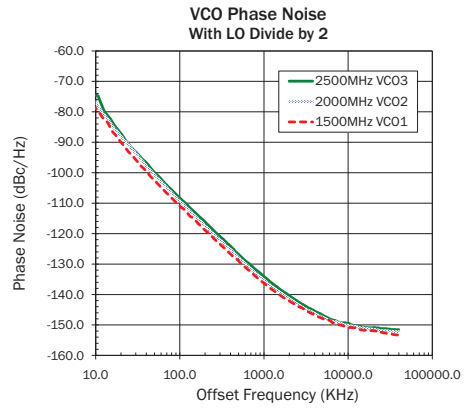
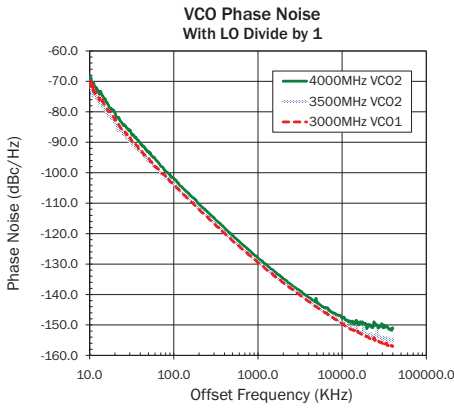
**Typical Performance Characteristics: Synthesizer**

$V_{DD}=+3V$  and  $T_A=+27\text{ }^\circ\text{C}$  unless stated.



## Typical Performance Characteristics: Synthesizer and VCO

$V_{DD}=+3V$  and  $T_A=+27\text{ }^\circ\text{C}$  unless stated.



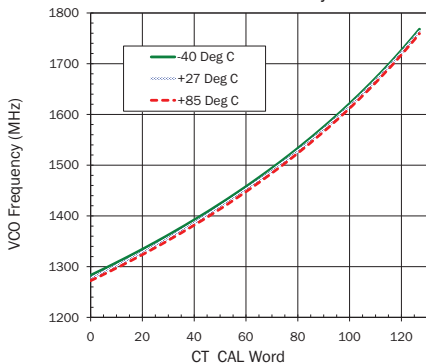
Note:

- 26MHz Crystal Oscillator: NDK ENA3523A
- 52MHz Crystal Oscillator: NDK ENA3560A

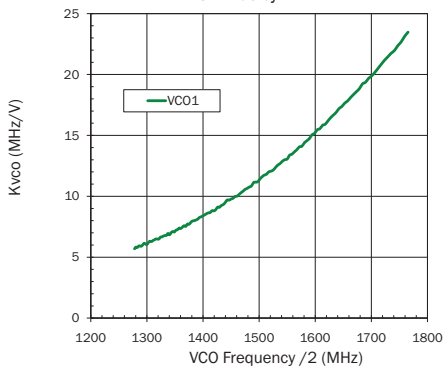
**Typical Performance Characteristics: VCO**

$V_{DD} = +3V$  and  $T_A = +27^\circ C$  unless stated.

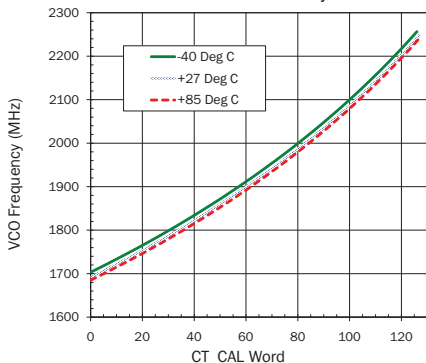
**VCO1 Frequency versus CT\_CAL**  
VCO1 with LO Divide by 2



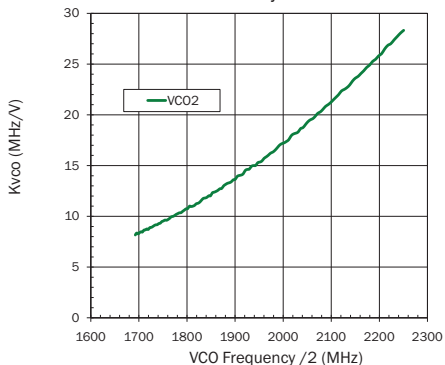
**VCO1 Frequency versus Kvco**  
LO Divide by 2



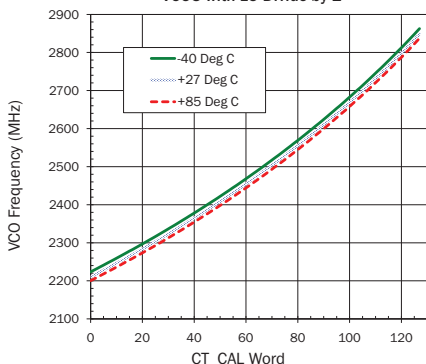
**VCO2 Frequency versus CT\_CAL**  
VCO2 with LO Divide by 2



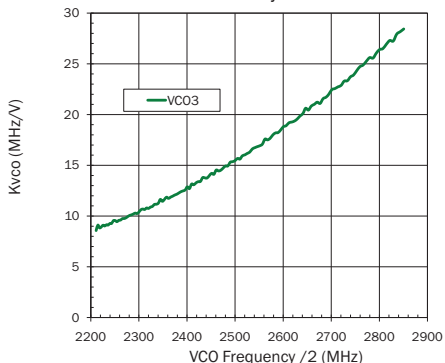
**VCO2 Frequency versus Kvco**  
LO Divide by 2



**VCO3 Frequency versus CT\_CAL**  
VCO3 with LO Divide by 2

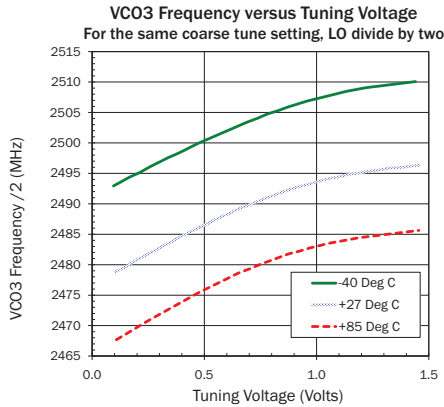
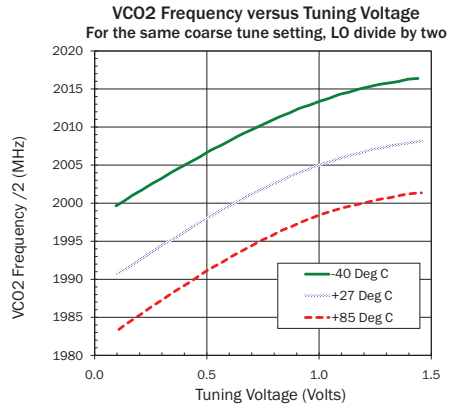
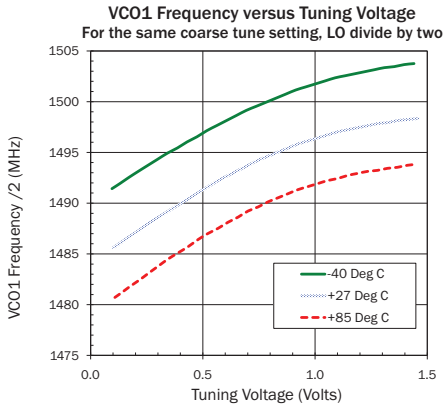


**VCO3 Frequency versus Kvco**  
LO Divide by 2



## Typical Performance Characteristics: VCO

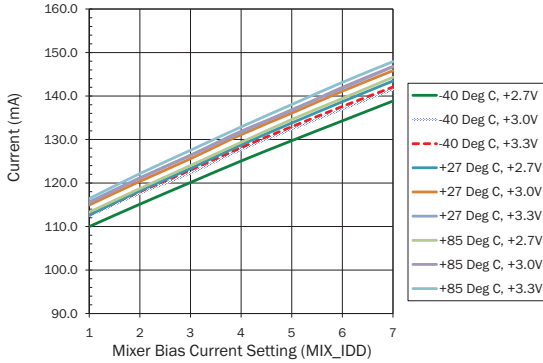
$V_{DD}=+3V$  and  $T_A=+27\text{ }^\circ\text{C}$  unless stated.



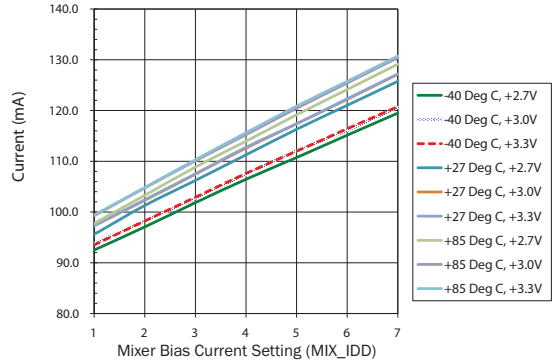
**Typical Performance Characteristics: Supply Current**

$V_{DD} = +3V$  and  $T_A = +27^\circ C$  unless stated. Typical Performance Characteristics: RFMixer 2, RFFC5071 and RFFC5072

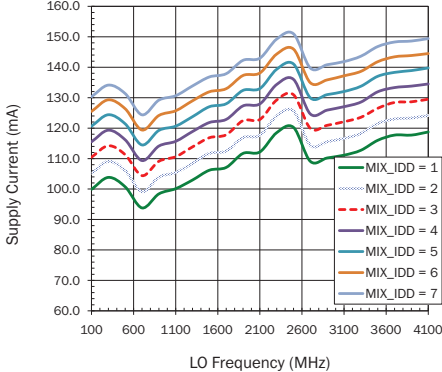
**Total Supply Current versus Mixer Bias Setting**  
One Mixer Enabled, LO Frequency = 3500MHz



**Total Supply Current versus Mixer Bias Setting**  
One Mixer Enabled, LO Frequency = 1000MHz



**Total Supply Current versus LO Frequency**  
One Mixer Enabled, +3.0V Supply Voltage



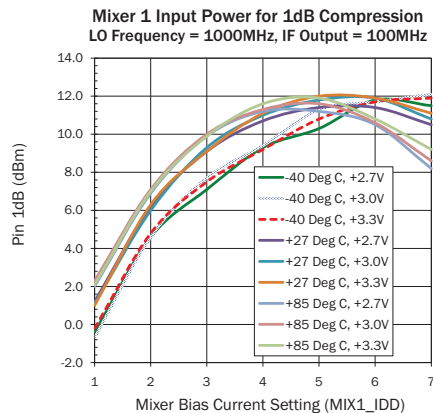
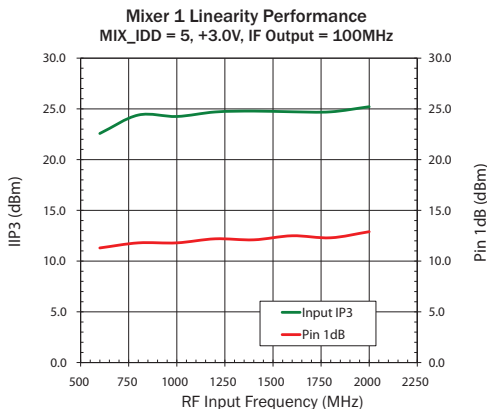
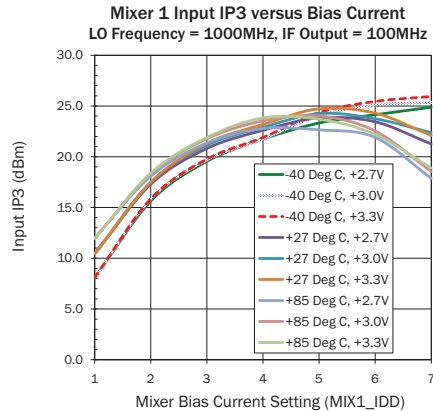
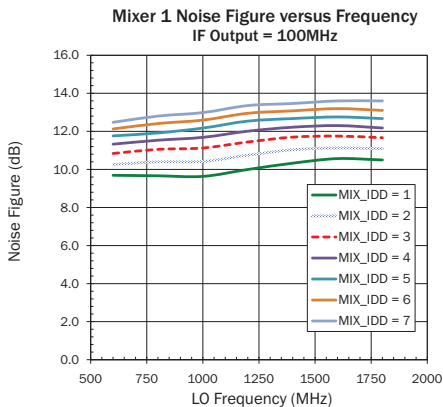
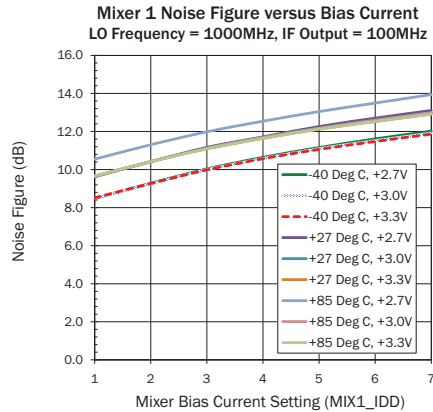
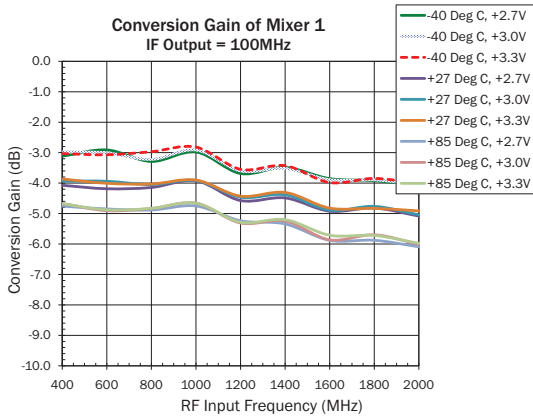
**RFFC5071 Typical Operating Current in mA**  
in Full Duplex Mode (both mixers enabled) with +3V supply.

| MIX2_IDD | MIX1_IDD |     |     |     |     |     |     |
|----------|----------|-----|-----|-----|-----|-----|-----|
|          | 1        | 2   | 3   | 4   | 5   | 6   | 7   |
| 1        | 121      | 126 | 131 | 136 | 142 | 146 | 151 |
| 2        | 126      | 131 | 136 | 141 | 147 | 151 | 156 |
| 3        | 131      | 136 | 141 | 147 | 152 | 156 | 161 |
| 4        | 136      | 141 | 147 | 152 | 157 | 162 | 167 |
| 5        | 141      | 146 | 152 | 157 | 162 | 167 | 172 |
| 6        | 146      | 151 | 156 | 161 | 167 | 171 | 176 |
| 7        | 151      | 156 | 161 | 166 | 171 | 176 | 181 |

## Typical Performance Characteristics: RF Mixer 1, RFFC5071 only

$V_{DD} = +3V$  and  $T_A = +27^\circ C$  unless stated. As measured on RFFC5071 wideband evaluation board.

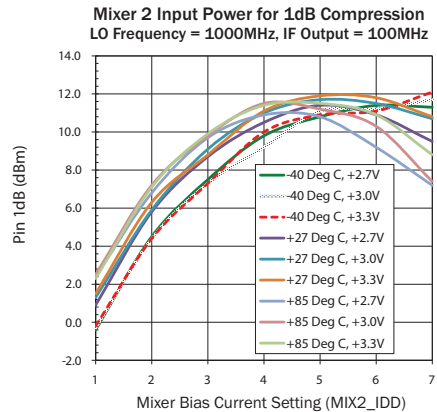
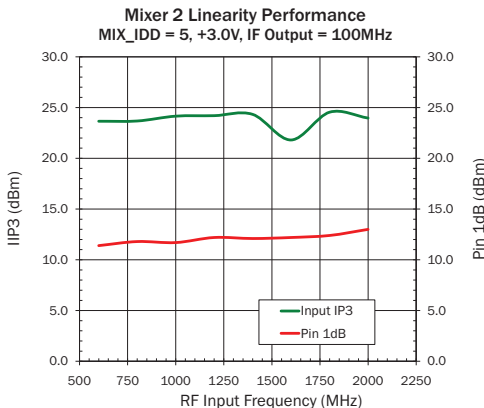
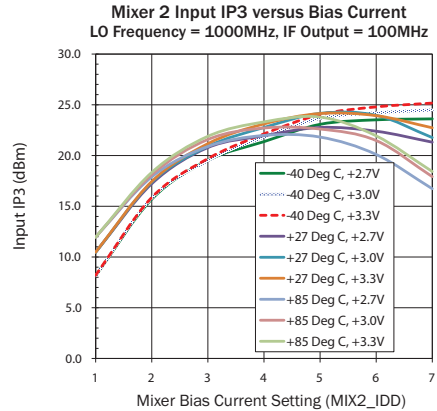
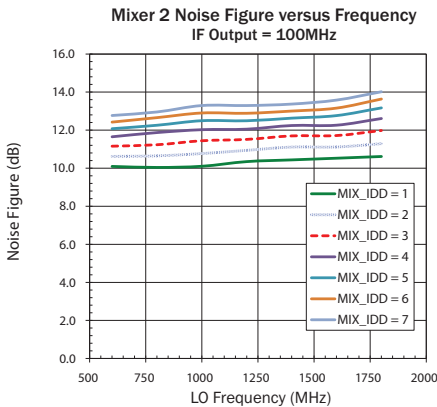
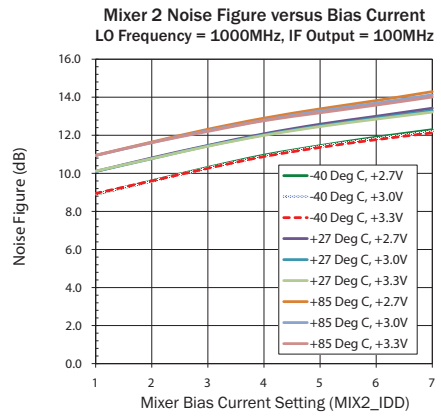
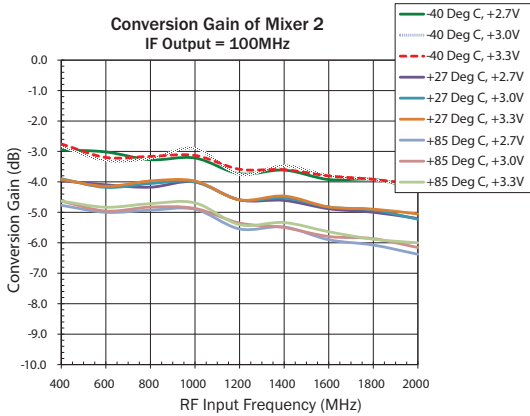
See application schematic on page 7.



**Typical Performance Characteristics: RF Mixer 2, RFFC5071 and RFFC5072**

$V_{DD}=+3V$  and  $T_A=+27^\circ C$  unless stated. As measured on RFFC5071/5072 wideband evaluation board.

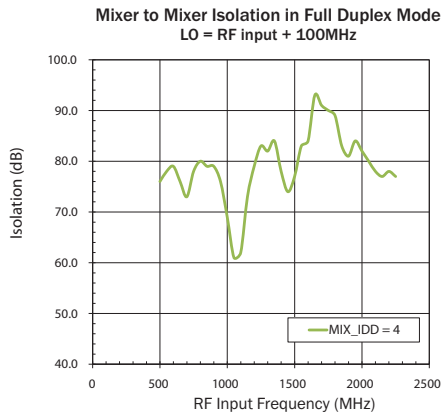
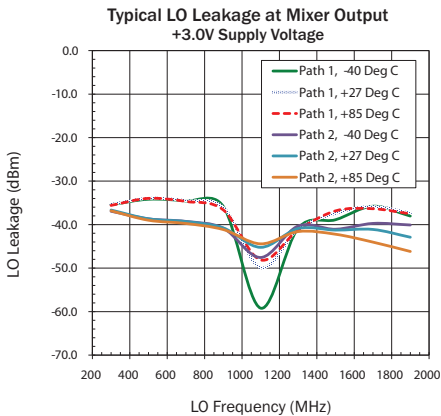
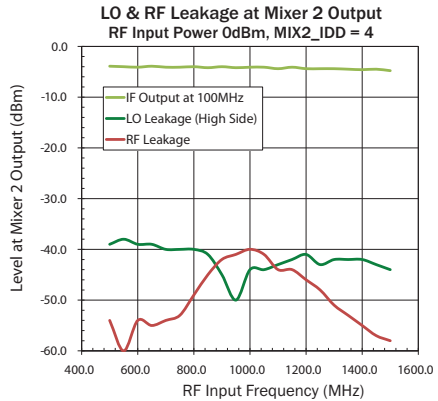
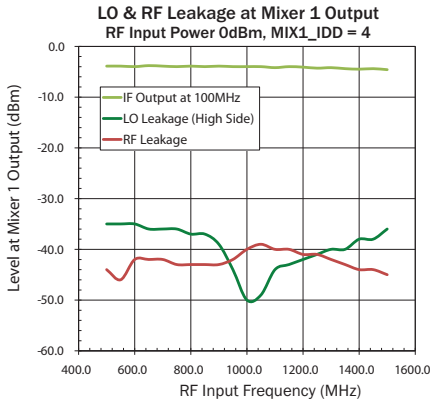
See application schematic on page 7.



## Typical Performance Characteristics: RF Mixers, RFFC5071 and RFFC5072

$V_{DD} = +3V$  and  $T_A = +27^\circ C$  unless stated. As measured on RFFC5071 wideband evaluation board.

See application schematic on page 7. Note: Mixer 1 plots only apply to RFFC5071.

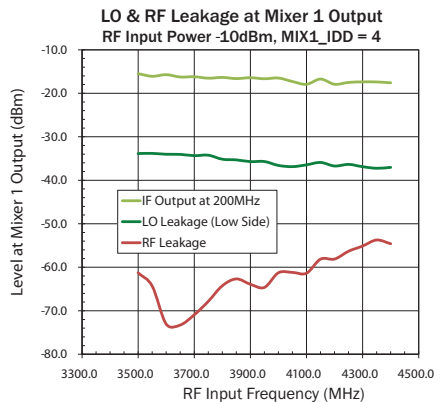
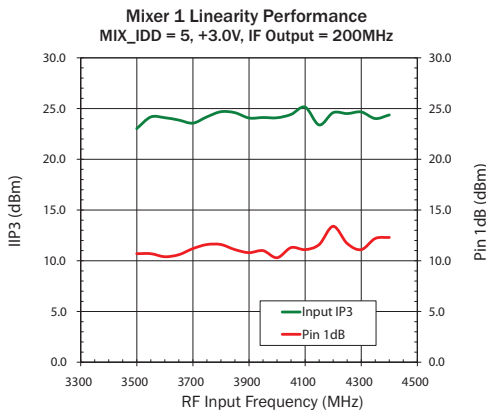
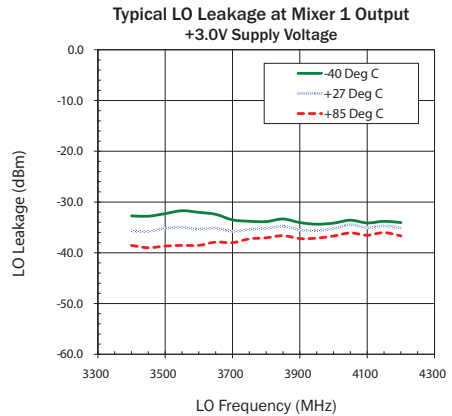
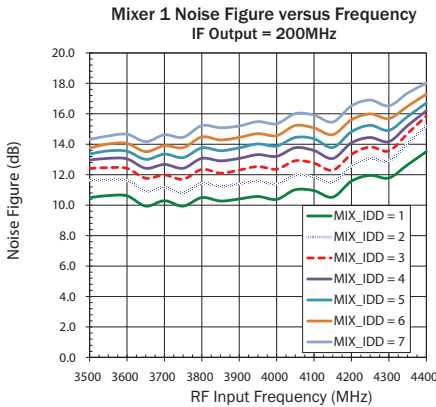
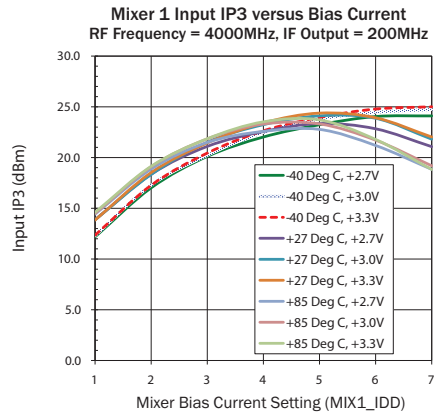
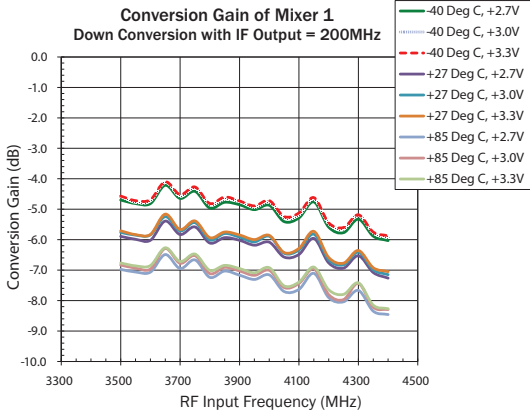




**Typical Performance Characteristics: RF Mixers at 3.7 GHz**

$V_{DD} = +3V$  and  $T_A = +27^\circ C$  unless stated. As measured on 3.7 GHz narrowband evaluation board.

See application schematic on page 8.



## **Programming Information**

The RFFC5071 and RFFC5072 share a common serial interface and control block. Please refer to the following documents for further details on programming and control:

**Slice2 Register Map and Programming Guide**  
**Slice2 Mixer Programming Guide**

These documents are available for download from the RFMD web-site following the link below:

<http://rfmd.com/products/IntSynthMixer/>

## **Evaluation Boards**

The evaluation boards for the RFFC5071 and RFFC5072 are provided as part of a design kit, along with the necessary cables and programming software tool to enable full evaluation of the device. The standard evaluation boards are configured with 3.7 GHz ceramic baluns on the RF ports, and wideband transformers on the IF ports. The design kits can be ordered from [www.rfmd.com](http://www.rfmd.com) or from local RFMD sales offices and authorized sales channels. For ordering codes please refer to page 20.



## Ordering Information

### RFFC5071

| Part Number  | Description         | Devices/Container   |
|--------------|---------------------|---------------------|
| RFFC5071SB   | 32-pin QFN          | 5-piece sample bag  |
| RFFC5071SQ   | 32-pin QFN          | 25-piece sample bag |
| RFFC5071SR   | 32-pin QFN          | 100-piece reel      |
| RFFC5071TR7  | 32-pin QFN          | 750-piece reel      |
| RFFC5071TR13 | 32-pin QFN          | 2500-piece reel     |
| DKFC5071     | Complete Design Kit | 1 box               |

### RFFC5072

| Part Number  | Description         | Devices/Container   |
|--------------|---------------------|---------------------|
| RFFC5072SB   | 32-pin QFN          | 5-piece sample bag  |
| RFFC5072SQ   | 32-pin QFN          | 25-piece sample bag |
| RFFC5072SR   | 32-pin QFN          | 100-piece reel      |
| RFFC5072TR7  | 32-pin QFN          | 750-piece reel      |
| RFFC5072TR13 | 32-pin QFN          | 2500-piece reel     |
| DKFC5072     | Complete Design Kit | 1 box               |